



### **Product Features:**

тсхо Low Jitter, Non-PLL Based Output CMOS Output Compatible with Leadfree Processing Digital Compensation

## **Applications:**

Wireless Communication Test Instruments GPS Base stations Telecommunications

Frequency	8.000 MHz to 40.000 MHz		
Output Level			
CMOS	"0" = 0.5 Vdc Max.		
	(1) = 80% of Vcc Min.		
Output Load	15pF		
Duty Cycle	50% +10%		
Duty Cycle			
Rise / Fall Time	10 nS Max		
Frequency Stability			
Vs Temperature	See Frequency Stability Table		
Vs Voltage (±5%)	±0.3 ppm Max.		
Vs Load (±5%)	±0.2 ppm Max.		
Frequency Tolerance	±1.0 ppm Max.		
@ 25° C			
Aging	±1 ppm / Year Max.		
@ 25° C			
Supply Voltage	See Supply Voltage Table, Tolerance ± 5%		
Supply voltage	See Supply voltage Table, Tolerance ± 5%		
Current	6.0 mA Max		
Current			
Operating	See Operating Temperature Table		
oporating			
Storage	-40° C to +85° C		
<b>U</b> *			
Phase Noise	-86 dBc/Hz @ 10 Hz		
(Typ. @ 20Mhz)	-115 dBc/Hz @ 100 Hz		
, , ,	-138 dBc/Hz @ 1KHz		
	-146 dBc/Hz @ 10KHz		



**Dimension Units: mm** 

Part Number Guide		Sample Part Number: I538-1Q3- 20.000 MHz		
Package	Operating Temperature	Frequency Stability vs Temperature	Supply Voltage	Frequency
I538 (CMOS TCXO)	7 = 0°C to +50°C	**N = ±1.0 ppm	2 = 2.7 V	-20.000 MHz
	1 = 0°C to +70°C	**O = ±1.5 ppm	3 = 3.3 V	
	3 = -20°C to +70°C	P = ±2.0 ppm	6 = 2.5 V	
	5 = -30°C to +85°C	Q = ±2.5 ppm	7 = 3.0 V	
	2 = -40°C to +85°C	R = ±3.0 ppm	8 = 2.8 V	
		J = ±5.0 ppm		

NOTE:

A 0.01 µF bypass capacitor is recommended between Vcc (pin 4) and GND (pin 2) to minimize power supply noise. \*\* Not available for all operating temperature ranges and output frequencies.

# **I538 Series**



## Pb Free Solder Reflow Profile:

**Typical Application:** 



\*Units are backward compatible with 240C reflow processes

#### **Package Information:**

MSL = N.A. (package does not contain plastic; storage life is unlimited under normal room conditions). Termination = e4 (Au over Ni over W base metallization).

### **Tape and Reel Information:**



Quantity per Reel	3000
Α	8 ± 0.3
В	4 ± 0.2
C	$3.5 \pm 0.2$
D	9±1 or 12 ± 3
E	60 / 80
F	180

## **Environmental Specifications:**

MIL-STD-883, Method 1011, Condition A
MIL-STD-883, Method 1004
MIL-STD-883, Method 2002, Condition B
MIL-STD-883, Method 2007, Condition A
J-STD-020C, Table 5-2 Pb-free devices (except 2 cycles max)
Pb-Free / RoHS / Green Compliant
JESD22-B102-D Method 2 (Preconditioning E)
MIL-STD-883, Method 2004, Test Condition D
MIL-STD-883, Method 1014, Condition C
MIL-STD-883, Method 1014, Condition A2, R1=2x10-8 atm cc/s
MIL-STD-202, Method 215